

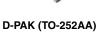


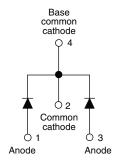
Vishay Semiconductors

COMPLIANT

Schottky Rectifier, 2 x 3 A







PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	2 x 3 A					
V_{R}	50 V, 60 V					
V _F at I _F	0.65 V					
I _{RM}	15 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	6 mJ					

FEATURES

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-MBRD650CTPbF, VS-MBRD660CTPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	6	А					
V _{RRM}		50/60	V					
I _{FSM}	t _p = 5 μs sine	490	А					
V _F	3 Apk, T _J = 125 °C (per leg)	0.65	V					
TJ	Range	- 40 to 150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRD650CTPbF	VS-MBRD660CTPbF	UNITS				
Maximum DC reverse voltage	V_{R}	50	60	V				
Maximum working peak reverse voltage	V_{RWM}	50	00	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER SYMBOL			TEST CONDIT	TEST CONDITIONS		UNITS		
Maximum average forward current	per leg		50 % duty cycle at T _C = 128 °C, rectangular waveform		3.0			
See fig. 5			6	Α				
Maximum peak one cycle non-repetitive surge current See fig. 7		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	^		
			10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75			
Non-repetitive avalanche energy per leg E_{AS} $T_{J} = 25$ °C, I_{AS}		$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 12 \text{mH}$		6	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		0.6	Α		

Document Number: 94314 Revision: 14-Jan-11

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		3 A	T _{.1} = 25 °C	0.7	V			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	6 A	11 = 23 0	0.9				
See fig. 1	V FM (*)	3 A	T _{.1} = 125 °C	0.65				
		6 A	1J = 125 C	0.85				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.1	mA			
See fig. 2		T _J = 125 °C	v _R = nateu v _R	15				
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		145	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.0	nΗ			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance,	per leg	р	DC operation	6			
junction to case	per device	R_{thJC}	See fig. 4	3	°C/W		
Maximum thermal resistance, junction to ambient		R _{thJA}		80	3,11		
Ai				0.3	g		
Approximate weight				0.01	OZ.		
Moulting devices			Coop at the D. DAIX (similar to TO 050AA)	MBRD650CT			
Marking device			Case style D-PAK (similar to TO-252AA)	MBRD660CT			

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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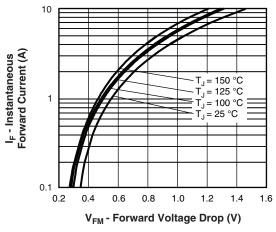


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

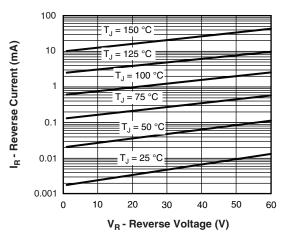


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

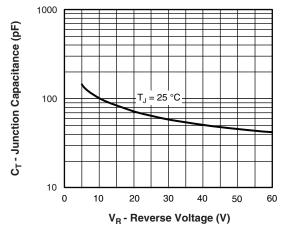


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

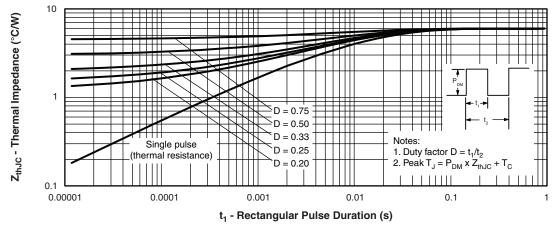


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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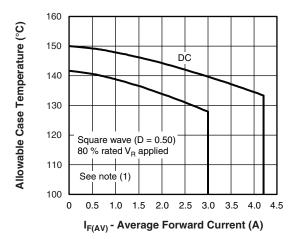


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

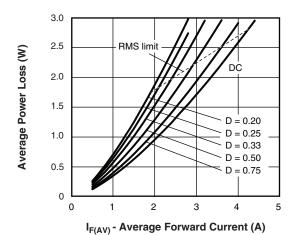


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

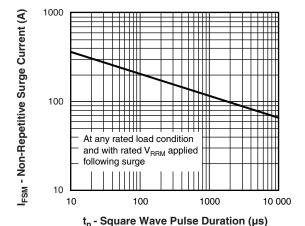


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

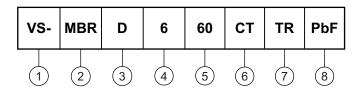
VS-MBRD650CTPbF, VS-MBRD660CTPbF

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - D = TO-252AA (D-PAK)

- Current rating (6 = 6 A)

50 = 50 V 50 = 60 V

6 - CT = Center tap (dual)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - PbF = Lead (Pb)-free

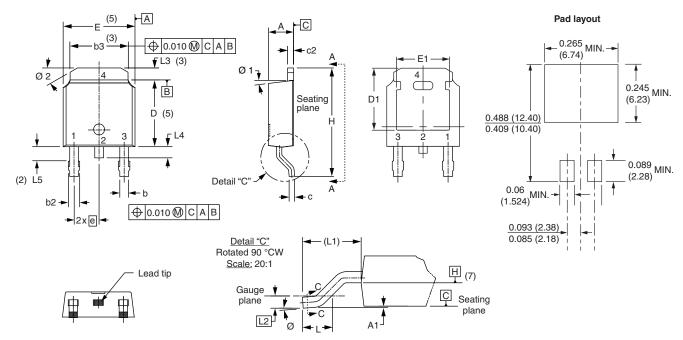
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					



Vishay Semiconductors

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIBUL	MIN.	MAX.	
Α	2.18	2.39	0.086	0.094		е	2.29	BSC	
A1	-	0.13	-	0.005		Н	9.40	10.41	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	
b2	0.76	1.14	0.030	0.045		L1	2.74	BSC	
b3	4.95	5.46	0.195	0.215	3	L2	0.51	BSC	
С	0.46	0.61	0.018	0.024		L3	0.89	1.27	
c2	0.46	0.89	0.018	0.035		L4	1	1.02	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	
D1	5.21	-	0.205	-	3	Ø	0°	10°	
Е	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	
E1	4.32	-	0.170	=	3	Ø2	25°	35°	

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
е	2.29 BSC		0.090	BSC		
Н	9.40	10.41	0.370	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74 BSC		0.108 REF.			
L2	0.51 BSC		0.020 BSC			
L3	0.89	1.27	0.035	0.050	3	
L4	ı	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060	2	
Ø	0°	10°	0°	10°		
Ø1	0°	15°	0°	15°		
Ø2	25°	35°	25°	35°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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Revision: 02-Oct-12 Document Number: 91000